

General Description

The MAX5900/MAX5901 are SOT23/TDFN hot-swap controllers that allow a circuit card to be safely hot-plugged into a live backplane without causing a glitch on the power-supply rail. These devices operate from -9V to -100V and provide the simplest hot-swap solution by eliminating all external components except an external n-channel MOSFET.

The MAX5900/MAX5901 limit the inrush current to the load and provide a circuit-breaker function for overcurrent protection. During startup, the circuit-breaker function is disabled and the MAX5900/MAX5901 limit the inrush current by gradually turning on the external MOSFET. Once the external MOSFET is fully enhanced, the circuit-breaker function is enabled and the MAX5900/MAX5901 provide overcurrent protection by monitoring the voltage drop across the external MOSFET's on-resistance.

The MAX5900/MAX5901 include an undervoltage lockout (UVLO) function, ON/OFF control input, and a powergood status output, PGOOD (MAX5900) or PGOOD (MAX5901). A built-in thermal shutdown feature is also included to protect the external MOSFET in case of overheating.

The MAX5900/MAX5901 offer latched or autoretry fault management and are available with 200mV, 300mV, or 400mV circuit-breaker thresholds. Both the MAX5900 and MAX5901 are available in small SOT23 and TDFN packages, and are specified for the extended -40°C to +85°C temperature range. For specific ordering information see the Selector Guide at the end of the data sheet.

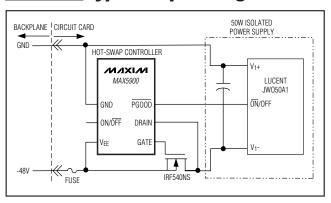
Applications

Telecom Line Cards **Network Routers** Base-Station Line

Cards

Network Switches Servers

Typical Operating Circuits



Features

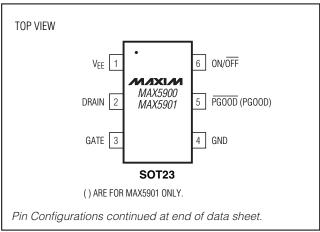
- ♦ Wide -9V to -100V Operation
- **♦** Requires No External Sense Resistor
- **♦ Drives External N-Channel MOSFET**
- ♦ Limits Inrush Current
- **♦ Circuit-Breaker Function**
- Less than 1mA Quiescent Current
- ♦ ON/OFF Input Permits Load Power-Supply Control and Sequencing
- ♦ Adjustable Undervoltage Lockout
- ♦ Power-Good Output with 100V Rating
- **♦ Latching or Automatic Retry Fault Management**
- Thermal Shutdown Helps Protect the External **MOSFET**
- ♦ Space-Saving 6-Pin SOT23 and TDFN Packages

Ordering Information

PART	TEMP RANGE	PIN- PACKAGE	PKG CODE
MAX5900EUT+T*	-40°C to +85°C	6 SOT23-6	U6F-6
MAX5900ETT+T*	-40°C to +85°C	6 TDFN-EP**	T633-2
MAX5901 EUT+T*	-40°C to +85°C	6 SOT23-6	U6F-6
MAX5901ETT+T*	-40°C to +85°C	6 TDFN-EP**	T633-2

^{*}For specific part numbers, see Selector Guide at end of data

Pin Configurations



Typical Operating Circuits continued at end of data sheet.

Simple Swapper is a trademark of Maxim Integrated Products, Inc.

Maxim Integrated Products 1

⁺Denotes lead-free package.

^{**}EP = Exposed pad.

ABSOLUTE MAXIMUM RATINGS

Terminal Voltage (with respect	
	120V to +0.3V
ON/OFF to VEE	0.3V to +4V
GATE to VEE	0.3V to +12V
Current into Any Pin	±3mA

Continuous Power Dissipation ($T_A = +70^{\circ}C$)	
6-Pin SOT23 (derate 9.1mW/°C above +70°C)727m	١W
6-Pin TDFN (derate 18.2mW/°C above +70°C)1454m	١W
Junction to Case Thermal Resistance, θ_{JC} (TDFN)8.5°C/	/W
Maximum Junction Temperature+150	°C
Storage Temperature Range60°C to +150°	°C
Lead Temperature (soldering, 10s)+300	°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

(VEE = -9V to -100V, GND = 0V, ON/ $\overline{\text{OFF}}$ open circuit, T_A = -40°C to +85°C, unless otherwise noted. Typical values are at V_{EE} = -48V and T_A = +25°C.) (Notes 1, 2)

PARAMETER	SYMBOL	CONDI	TIONS	MIN	TYP	MAX	UNITS	
Supply Voltage	VEE					-9	V	
Supply Current	IGND	Measured at GND			0.5	1.3	mA	
			$V_{EE} = -36V \text{ to } -72V$	7.5	9.5	11.6		
External Gate Drive	Vgs	V _{GATE} - V _{EE}	V _{EE} = -100V	8	10	11.6	V	
			V _{EE} = -9V	6	7			
Load Voltage Slew-Rate Magnitude	SR	I dV _{DRAIN} /dt I, C _{LOAD} = ⁻¹	10μF, V _{EE} = -9V to -36V	4.5	10	17	V/ms	
Default UVLO	V _U VLO	IV _{EE} I increasing		-34.5	-31.5	-28.5	V	
UVLO Hysteresis					3.5		V	
ON/OFF Input Resistance	Ron/OFF			20	32	50	kΩ	
Drain to VEE Resistance	RDVEE			466		kΩ		
ON/OFF Reference Threshold	V _{ON/OFF}	(V _{ON/OFF} - V _{EE}) increasing		1.14	1.26	1.38	V	
ON/OFF Hysteresis					140		mV	
Start Delay (Note 3)	ton			150	300	500	ms	
ON/OFF Off Delay (Note 4)	toff	VGATE - VEE < 1V		9	20	32	ms	
0: ". "			MAX590AEUT	170	200	240		
Circuit-Breaker Threshold	V _{CB} V _{DRAIN} - V _{EE}	V _{DRAIN} - V _{EE}	MAX590BEUT	265	300	345	mV	
Threshold	SHOID		MAX590CEUT	365	400	455		
		(V _{DRAIN} - V _{EE}) > V _{CB}	C _{GATE} = 1nF		1.5	3		
Circuit-Breaker Delay (Note 5)	t _{CB} until (V _{GATE} - V _{EE}) < 1V, 200mV overdrive	CGATE = 4.7nF		2.5	4.5	μs		
(Note 3)		step	CGATE = 10nF		4	6		
Restart Delay (Note 3)	trs	After circuit-breaker ever	nt, MAX590_A_EUT only	150	300	500	ms	

__ /N/XI/M

ELECTRICAL CHARACTERISTICS (continued)

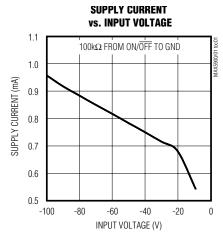
 $(V_{EE} = -9V \text{ to } -100V, \text{GND} = 0V, \text{ON}/\overline{\text{OFF}} \text{ open circuit}, T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}, \text{ unless otherwise noted.}$ Typical values are at $V_{EE} = -48V \text{ and } T_A = +25^{\circ}\text{C}.)$ (Notes 1, 2)

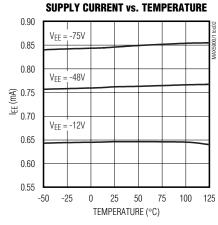
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
PGOOD (PGOOD) Assertion Threshold (Note 6)	VPG	V _{DRAIN} - V _{EE} ; MAX590_A, MAX590_L only	C).75 × V _{CB}		mV
PGOOD (PGOOD) Output Low Voltage	V _{OL}	MAX5900, V PGOOD - V _{EE} , I _{OL} = 1mA; MAX5901, V _{PGOOD} - V _{EE} , I _{OL} = 1mA		0.6	1.65	V
Power-Good Output Open- Drain Leakage Current	ГОН	V PGOOD - VEE = 100V (MAX5900); VPGOOD - VEE = 100V (MAX5901)		0.2	10	μΑ
Thermal Shutdown Temperature	T _{SD}	Junction temperature		+125		°C
Thermal Shutdown Hysteresis	T _{HY}			15		°C

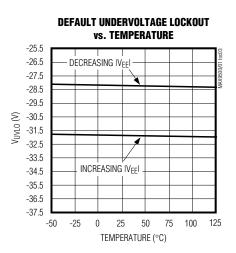
- **Note 1:** All currents into device pins are positive, all currents out of device pins are negative, and all voltages are referenced to GND, unless otherwise noted.
- Note 2: All specifications are 100% tested at T_A = +25°C. Specifications over -40°C to +85°C are guaranteed by characterization.
- Note 3: This is the delay time from a valid on condition until V_{GS} begins rising. Valid on conditions are: the device is not in undervoltage lockout; ON/OFF is not driven low; and the device is not in thermal shutdown.
- Note 4: This is the delay from a valid low on ON/OFF until VGS falls. Pulses on ON/OFF less than toFF are ignored, offering glitch immunity.
- Note 5: Guaranteed by design, not production tested.
- Note 6: For a detailed description, see the Power-Good Output section.

Typical Operating Characteristics

(VEE = -48V, GND = 0V, and TA = +25°C, unless otherwise noted. See Figure 6 for test circuits.)

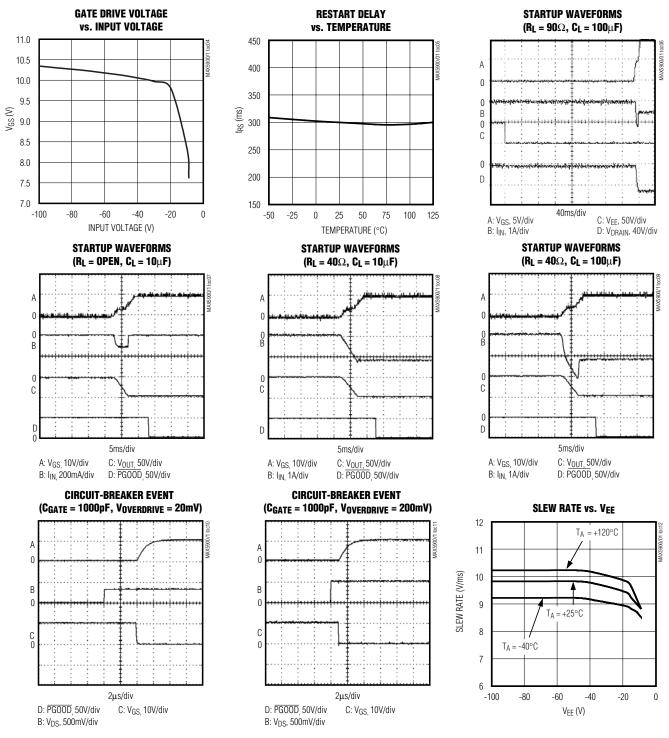






Typical Operating Characteristics (continued)

(VEE = -48V, GND = 0V, and T_A = +25°C, unless otherwise noted. See Figure 6 for test circuits.)



Pin Description

PIN		NAME	FUNCTION	
MAX5900	MAX5901	NAME	FUNCTION	
1	1	V _{EE}	Negative Supply Voltage Input and External n-Channel MOSFET Source Connection	
2	2	DRAIN	Drain Sense Input for External n-Channel MOSFET. Connect DRAIN as close as possible to the MOSFET's drain and use wide circuit traces to assure good thermal coupling between the MAX5900/MAX5901 and the MOSFET (see the Layout Guidelines section).	
3	3	GATE	Gate Drive Output for External n-Channel MOSFET	
4	4	GND	Ground Connection.	
5	_	PGOOD	Power-Good Output. PGOOD is an n-channel, open-drain, active-low output, referenced to VEE.	
_	5	PGOOD	Power-Good Output. PGOOD is an n-channel, open-drain, active-high output, referenced to VEE.	
6	6	ON/OFF	ON/OFF Control Input. ON/OFF is referenced to V _{EE} . Drive ON/OFF above 1.38V or leave unconnected to enable the device. Drive ON/OFF below 1V to disable the device. ON/OFF is also used to adjust the UVLO threshold. See the <i>Under-voltage Lockout</i> section in the <i>Applications Information</i> . Internally clamped to nominally 3V through a $1k\Omega$ resistor (see Figure 1).	
_	_	EP	Exposed Pad (TDFN only). Connect to VEE.	

Detailed Description

The MAX5900/MAX5901 are integrated hot-swap controller ICs contained in 6-pin SOT23/TDFN packages. They allow a board to be safely hot plugged into a live backplane without causing a glitch on the power-supply rail. They are well suited for -48V telecom power systems, allowing a cost-effective, simple, and compact design. The MAX5900/MAX5901 operate from -9V to -100V to cover the standard telecom voltage range, and to serve more generalized applications. These devices require only an external n-channel power MOS-FET to provide hot-swap control. Figure 1 shows a functional diagram of the MAX5900/MAX5901.

The MAX5900/MAX5901 control an external n-channel power MOSFET placed in the negative power-supply pathway. When power is first applied, the MAX5900/MAX5901 keep the MOSFET turned off. The MAX5900/MAX5901 hold the MOSFET off indefinitely if ON/OFF is held low, if the supply voltage is below the undervoltage lockout level, or if the die temperature exceeds +125°C. If none of these conditions exist for 300ms (typ), the MAX5900/MAX5901 begin to gradually turn on the MOSFET. During this turn-on phase, the MAX5900/MAX5901 slowly enhance the MOSFET,

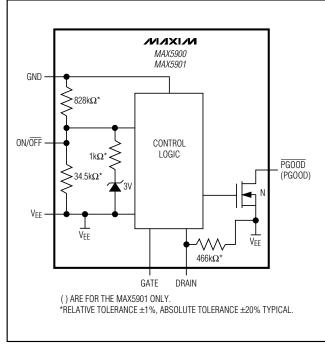


Figure 1. Functional Diagram

allowing the voltage on the load, i.e. the drain of the MOSFET, to fall no faster than 10V/ms (typ). The inrush current to the load is thus limited to a level proportional to the load capacitance, and the constant load voltage slew rate. After the MOSFET is fully enhanced, and the load voltage is settled to its final value, the MAX5900A/ MAX5901A and MAX5900L/MAX5901L monitor the voltage drop from the MOSFET's drain-to-source (VDS). If the voltage drop exceeds 75% of the circuit-breaker threshold the MAX5900A/MAX5901A or MAX5900L/ MAX5901L turn off the MOSFET, disconnecting the load immediately. Because the circuit-breaker function is not activated until the MOSFET is fully enhanced, it takes approximately 10ms for the MAX5900A/ MAX5901A or MAX5900L/MAX5901L to react to an output short circuit at startup. If no circuit-breaker fault exists, the power-good output is asserted. Then, if any of four conditions exist, the power-good output deasserts and the MOSFET is turned off . The four conditions are: the voltage across the MOSFET exceeds the circuit-breaker threshold; the supply voltage magnitude falls below the undervoltage lockout level; the die temperature exceeds +125°C; or ON/OFF is forced low. After a circuit-breaker fault, the MAX5900L/MAX5901L keep the MOSFET off until the power is cycled, or the part is reset by toggling ON/OFF low for at least 20ms (typ). After a circuit-breaker fault, the MAX5900A/ MAX5901A automatically restart in 300ms (typ). All versions automatically restart after a thermal fault, or an undervoltage shutdown, if the fault condition goes away for at least 300ms (typ).

ON/OFF offers external control of the MAX5900/MAX5901, facilitating power-supply sequencing, and may also be used to change the UVLO level. UVLO keeps the external MOSFET switched off as long as the magnitude of the input voltage is less than a desired level.

A power-good output, $\overline{\text{PGOOD}}$ (MAX5900) or PGOOD (MAX5901), asserts when the external MOSFET is fully enhanced and the drain-source voltage is at least 25% below the circuit-breaker threshold. $\overline{\text{PGOOD}}$ and PGOOD are open-drain outputs referenced to VEE, and can withstand up to 100V above VEE.

A thermal shutdown feature protects the external MOS-FET by turning it off if the die temperature of the MAX5900/MAX5901 exceeds +125°C. The MAX5900/MAX5901 must be in good thermal contact with the external MOSFET. See the *Layout Guidelines* section in the *Applications Information*.

A circuit-breaker function monitors the voltage across the external MOSFET, V_{DS}, and turns off the MOSFET if V_{DS} exceeds the circuit-breaker threshold, V_{CB}. The

circuit-breaker function is enabled after the MOSFET is fully enhanced. Three threshold voltage options are available—200mV, 300mV, and 400mV. One version is available with no circuit-breaker function. circuit-breaker fault management for the MAX5900/MAX5901 is offered with two different configurations—latched and automatic retry.

Latched Circuit Breaker

After a circuit-breaker trip event, the latched versions (MAX5900L/MAX5901L) drive GATE to VEE, turning off the external MOSFET, and PGOOD (PGOOD) is deasserted. A latched-off condition needs to be reset by toggling ON/OFF low for at least 20ms, or by cycling the power supply, VEE.

Automatic Retry Circuit Breaker

After a circuit-breaker trip event, the automatic retry versions (MAX5900A/MAX5901A) drive GATE to VEE, turning off the external MOSFET, and \overrightarrow{PGOOD} (PGOOD) is deasserted. If the start conditions are met for a full 300ms (tRS) the start sequence is initiated. The start conditions are: the device is not in UVLO; ON/ \overrightarrow{OFF} is not driven low; and the device is not in thermal shutdown.

No Circuit Breaker

For the versions without a circuit-breaker MAX5900N (MAX5901N), PGOOD (PGOOD) is asserted when the MOSFET is fully enhanced. Once powered up, the MAX5900N/MAX5901N ignore the MOSFET drain-to-source voltage (VDS) for applications where a circuit-breaker function is not desired.

Applications Information

ON/OFF Control Input

The ON/OFF control input provides three hot-swap functions: external ON/OFF control; setting of the UVLO level; and resetting after a circuit-breaker event has caused the MAX5900L/MAX5901L to turn off the external MOSFET. Pulling ON/OFF to VEE for at least 20ms (toff) forces the MAX5900/MAX5901 to turn off the external MOSFET (see Figure 2 for a circuit example). To reset the MAX5900L/MAX5901L after a circuit-breaker event, toggle ON/OFF to VEE for at least 20ms (toff).

ON/ $\overline{\text{OFF}}$ can be used to sequence power supplies. Connecting a capacitor from ON/ $\overline{\text{OFF}}$ to VEE will delay the rise of ON/ $\overline{\text{OFF}}$ proportional to the capacitance and input impedance of ON/ $\overline{\text{OFF}}$, typically 32k Ω (Figure 3).

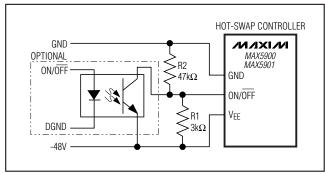


Figure 2. Programmed -20V Lockout With Optional Optocoupler On/Off Control

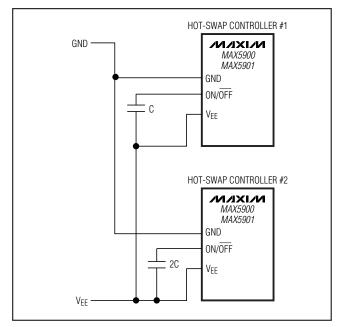


Figure 3. Power-Supply Sequencing

Turn-On and Turn-Off Delays

After power is applied, or ON/\overline{OFF} is released, there is a 300ms delay (ton) before the gate ramp is started. This delay is also the automatic restart time delay.

In the event of a circuit-breaker condition or an over-temperature fault condition, the turn-off delay is less than 2µs. An undervoltage condition must exist for at least 20ms (tOFF) before the MAX5900/MAX5901 turn off the external MOSFET. ON/OFF must be held low for at least 20ms (tOFF) before the MAX5900/MAX5901 turn off the external MOSFET. Turn-off delay minimizes spurious shutdowns due to noisy signals or momentary

voltage spikes, as well as preventing accidental resetting of the circuit-breaker latch (MAX5900L/MAX5901L).

Thermal Shutdown

A thermal shutdown feature helps protect the external MOSFET. If the die temperature of the MAX5900/MAX5901 exceeds +125°C, the MOSFET is turned off. For accurate performance, the MAX5900/MAX5901 must be in close thermal contact with the external MOSFET (see the *Layout Guidelines* section). Due to the low power dissipation of the MAX5900/MAX5901, its junction temperature will typically be within a few degrees of the MOSFET. All versions of the MAX5900/MAX5901 automatically restart from a temperature fault when the junction temperature drops below +110°C.

Undervoltage Lockout

The MAX5900/MAX5901 turn off the external MOSFET if the magnitude of the input voltage is below the level set by ON/OFF for longer than 20ms (toff). If ON/OFF is left unconnected, the lockout voltage (VUVLO) defaults to -31.5V. VUVLO may also be set to any value within the power-supply range by using external resistors. To set the lockout voltage to a value between -9V and -100V, use a resistor-divider connected between GND and VEE, with the center node of the divider connected to ON/OFF. For example, use a $3k\Omega$ resistor (R1 in Figure 2) from ON/OFF to VEE and calculate the other resistor, R2, using:

$$R2 = R1 \times \left(\frac{V_{UVLO}}{1.26} - 1\right)$$

where V_{UVLO} is the desired lockout voltage, and V_{ON/OFF} is the ON/OFF reference threshold specified in the *Electrical Characteristics* table (typically 1.26V).

Figure 2 shows an example circuit with V_{UVLO} set for -20V. To defeat the UVLO, simply connect a single $100k\Omega$ resistor between ON/\overline{OFF} and GND, as shown in Figure 4.

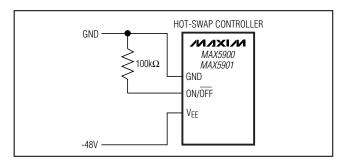


Figure 4. Defeating Undervoltage Lockout

Power-Good Output

The power-good output, \overline{PGOOD} (PGOOD), is opendrain and asserts when the external MOSFET is fully enhanced and VDS is less than VPG (75% of the circuitbreaker threshold, VCB). For versions without the circuitbreaker function (MAX5900N/MAX5901N), \overline{PGOOD} (PGOOD) asserts when the external MOSFET is fully enhanced.

PGOOD (PGOOD) deasserts within 2µs when a circuit-breaker event occurs or if the die temperature exceeds +125°C. PGOOD (PGOOD) deasserts if IVEEI < IVUVLOI for longer than 20ms or ON/OFF is held low for longer than 20ms.

The MAX5900 PGOOD is active-low and the MAX5901 PGOOD is active-high. Both are open-drain N-channel MOSFETs with their sources connected to VEE, and can withstand up to 100V.

Selecting a Circuit-Breaker Threshold

The MAX5900A/MAX5901A and the MAX5900L/MAX5901L offer a circuit-breaker function to protect the external MOSFET and the load from the potentially damaging effects of excessive current. As load current flows through the external MOSFET, a voltage, VDS, is generated from drain to source due to the MOSFET's on-resistance RDS(ON). The MAX5900A/MAX5901A and MAX5900L/MAX5901L monitor VDS when the external MOSFET is fully enhanced. If VDS exceeds the circuit-breaker threshold, the external MOSFET is turned off and PGOOD (PGOOD) is deasserted.

To accommodate different MOSFETs and different load currents, the MAX5900/MAX5901 are available with circuit-breaker threshold voltages of 200mV, 300mV, and 400mV

The circuit-breaker function is intended to disconnect the load if a gross overcurrent or short-circuit condition occurs. For calculating the circuit-breaker threshold, use the MOSFET's RON at the worst possible operating condition, and add a 25% overcurrent margin to the maximum circuit current. For instance, if a MOSFET has an R_{ON} of 0.06Ω at T_A = +25°C, and a normalized onresistance factor of 1.75 at TA = +130°C (from the MOSFET data sheet), the RON used for calculation is the product of these two numbers, or $(0.06\Omega) \times (1.75) =$ 0.105Ω . Then, if the maximum current is expected to be 2A, using a 25% margin, the current for calculation is $(2A) \times (1.25) = 2.5A$. The resulting minimum circuitbreaker threshold is then the product of these two results, or (0.105Ω) x (2.5A) = 0.263V. The next highest minimum available threshold is 0.265V of the MAX590_ _BEUT, which is an ideal choice given these parameters. Using this method to choose a circuitbreaker threshold allows the circuit to operate under worst-case conditions without causing a circuit-breaker fault, but the circuit-breaker function will still operate if a short-circuit or gross overcurrent condition occurs. See Table 1 for MOSFET suggestions. The MAX5900N/MAX5901N have no circuit-breaker function. For these parts choose an external MOSFET that meets the load requirements.

Determining Inrush Current

Determining a circuit's inrush current is necessary to help choose the proper MOSFET. The MAX5900/MAX5901 regulate the inrush current by means of controlling the load voltage slew rate, but inrush current is also a function of load capacitance. Determine inrush current using:

$$I = C \frac{dV}{dt} = C \times SR$$

where C is the load capacitance, and SR is the MAX5900/MAX5901 Load Voltage Slew-Rate Magnitude from the *Electrical Characteristics* table. For example, assuming a load capacitance of 100µF, and using the typical value of 10V/ms for the slew rate, the inrush current is 1A typical.

If the maximum possible Load Voltage Slew Rate is used, the maximum inrush current calculates to 1.7A. Choose a MOSFET with a maximum pulsed current specification that exceeds the maximum inrush current.

Suggested External MOSFETs

MAXIMUM I _{LOAD} (A)	SUGGESTED EXTERNAL MOSFET	SUGGESTED MAXIM PART
0.25	IRFL110	MAX590CEUT
0.5	IRFL4310	MAX590BEUT
1	IRFR3910	MAX590CEUT
2	IRF540NS	MAX590BEUT
3	IRF1310NS	MAX590BEUT
4	IRF1310NS	MAX590CEUT

 $V_{IN} = -9V \text{ to } -90V$

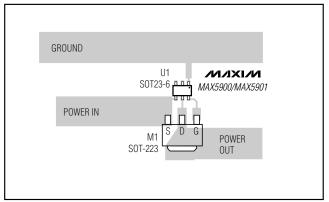


Figure 5. Circuit Board Layout Example

Layout Guidelines

Good thermal contact between the MAX5900/MAX5901 and the external MOSFET is essential for the thermal shutdown feature to operate effectively. Place the MAX5900/MAX5901 as close as possible to the drain of the external MOSFET, and use wide circuit board traces for good heat transfer. See Figure 5 for an example of a PC board layout.

Chip Information

TRANSISTOR COUNT: 678 PROCESS: BICMOS

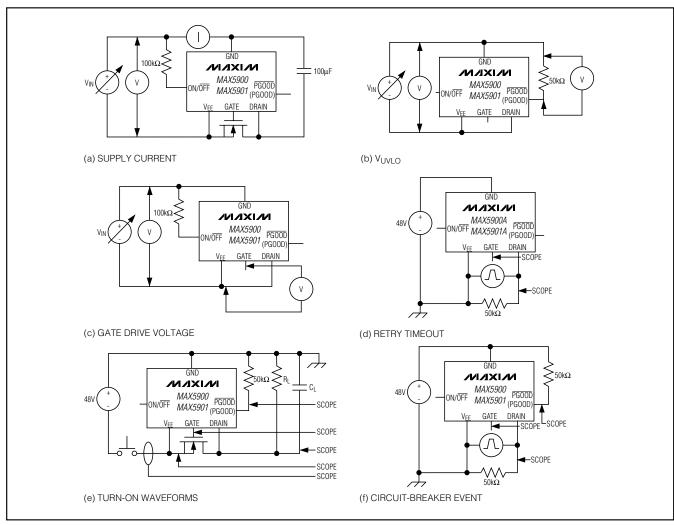


Figure 6. Test Circuits

Selector Guide

SOT23

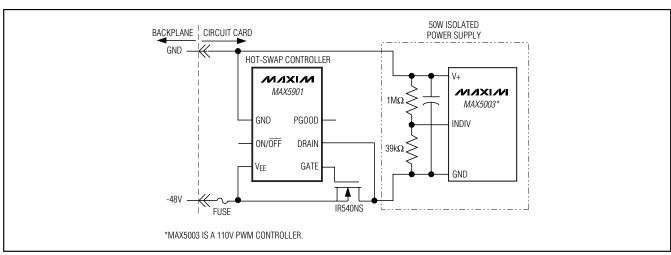
PART	CIRCUIT-BREAKER FUNCTION	CIRCUIT-BREAKER THRESHOLD (mV)	POWER-GOOD OUTPUT LOGIC	TOP MARK
MAX5900NNEUT+T	None	None	Active-Low	AAQV
MAX5900AAEUT+T	Autoretry	200	Active-Low	AAQJ
MAX5900ABEUT+T	Autoretry	300	Active-Low	AAQK
MAX5900ACEUT+T	Autoretry	400	Active-Low	AAQL
MAX5900LAEUT+T	Latched	200	Active-Low	AAQM
MAX5900LBEUT+T	Latched	300	Active-Low	AAQN
MAX5900LCEUT+T	Latched	400	Active-Low	AAQO
MAX5901NNEUT+T	None	None	Active-High	AAQW
MAX5901AAEUT+T	Autoretry	200	Active-High	AAQP
MAX5901ABEUT+T	Autoretry	300	Active-High	AAQQ
MAX5901ACEUT+T	Autoretry	400	Active-High	AAQR
MAX5901LAEUT+T	Latched	200	Active-High	AAQS
MAX5901LBEUT+T	Latched	300	Active-High	AAQT
MAX5901LCEUT+T	Latched	400	Active-High	AAQU

TDFN

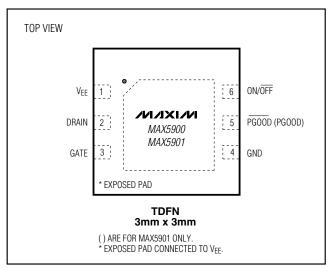
PART	CIRCUIT-BREAKER FUNCTION	CIRCUIT-BREAKER THRESHOLD (mV)	POWER-GOOD OUTPUT LOGIC	TOP MARK
MAX5900NNETT+T	None	None	Active-Low	AJT
MAX5900AAETT+T	Autoretry	200	Active-Low	AJU
MAX5900ABETT+T	Autoretry	300	Active-Low	AJV
MAX5900ACETT+T	Autoretry	400	Active-Low	AJW
MAX5900LAETT+T	Latched	200	Active-Low	AJX
MAX5900LBETT+T	Latched	300	Active-Low	AJY
MAX5900LCETT+T	Latched	400	Active-Low	AJZ
MAX5901NNETT+T	None	None	Active-High	AKA
MAX5901AAETT+T	Autoretry	200	Active-High	AKB
MAX5901ABETT+T	Autoretry	300	Active-High	AKC
MAX5901ACETT+T	Autoretry	400	Active-High	AKD
MAX5901LAETT+T	Latched	200	Active-High	AKE
MAX5901LBETT+T	Latched	300	Active-High	AKF
MAX5901LCETT+T	Latched	400	Active-High	AKG

⁺Denotes lead-free package.

Typical Operating Circuits (continued)

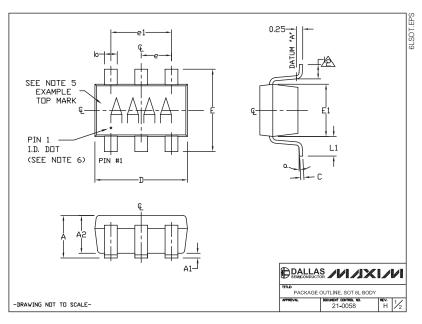


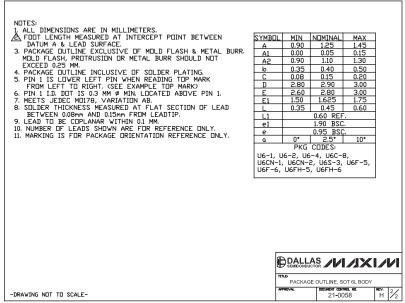
Pin Configurations (continued)



Package Information

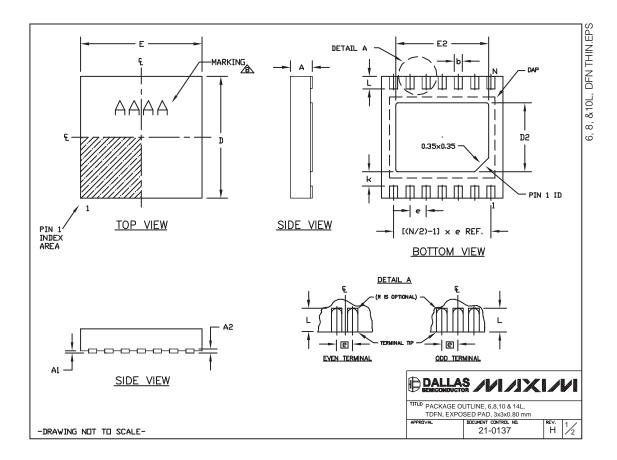
(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)





Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)



Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)

COMMON DIMENSIONS						
SYMBOL	MIN.	MAX.				
Α	0.70	0.80				
D	2.90	3.10				
E	2.90	3.10				
A1	0.00	0.05				
L	0.20	0.40				
k	0.25 MIN.					
A2	0.20 REF.					

PACKAGE VARIATIONS							
PKG. CODE	N	D2	E2	е	JEDEC SPEC	b	[(N/2)-1] x e
T633-1	6	1.50±0.10	2.30±0.10	0.95 BSC	MO229 / WEEA	0.40±0.05	1.90 REF
T633-2	6	1.50±0.10	2.30±0.10	0.95 BSC	MO229 / WEEA	0.40±0.05	1.90 REF
T833-1	8	1.50±0.10	2.30±0.10	0.65 BSC	MO229 / WEEC	0.30±0.05	1.95 REF
T833-2	8	1.50±0.10	2.30±0.10	0.65 BSC	MO229 / WEEC	0.30±0.05	1.95 REF
T833-3	8	1.50±0.10	2.30±0.10	0.65 BSC	MO229 / WEEC	0.30±0.05	1.95 REF
T1033-1	10	1.50±0.10	2.30±0.10	0.50 BSC	MO229 / WEED-3	0.25±0.05	2.00 REF
T1033-2	10	1.50±0.10	2.30±0.10	0.50 BSC	MO229 / WEED-3	0.25±0.05	2.00 REF
T1433-1	14	1.70±0.10	2.30±0.10	0.40 BSC		0.20±0.05	2.40 REF
T1433-2	14	1.70±0.10	2.30±0.10	0.40 BSC		0.20±0.05	2.40 REF

- NOTES:

 1. ALL DIMENSIONS ARE IN mm. ANGLES IN DEGREES.

 2. COPLANARITY SHALL NOT EXCEED 0.08 mm.

 3. WARPAGE SHALL NOT EXCEED 0.10 mm.

 4. PACKAGE LENGTH/PACKAGE WIDTH ARE CONSIDERED AS SPECIAL CHARACTERISTIC(S).

 5. DRAWING CONFORMS TO JEDEC MO229, EXCEPT DIMENSIONS "D2" AND "E2", AND T1433-1 & T1433-2.
- 6. "N" IS THE TOTAL NUMBER OF LEADS.
 7. NUMBER OF LEADS SHOWN ARE FOR REFERENCE ONLY.

 AMARKING IS FOR PACKAGE ORIENTATION REFERENCE ONLY.



-DRAWING NOT TO SCALE-

Revision History

Pages changed at Rev 5: 1-4, 10, 12-14

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 408-737-7600

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Hot Swap Voltage Controllers category:

Click to view products by Maxim manufacturer:

Other Similar products are found below:

LTC4227CUFD-4#PBF LTC4212IMS ADM1075-2ARUZ-RL7 LM5067MW-1/NOPB ADM1075-1ARUZ-RL7 MAX5969BETB+T

MIC22700YML-TR LTC4223CDHD-1#PBF MAX40200AUK+T LTC4224IDDB-2#TRMPBF LT1640LIS8#PBF LTC4217CDHC-12#PBF

LT1640ALCS8#PBF LT4294HDD#PBF LTC4253CGN#PBF LTC4211CMS8#PBF LTC4230CGN#PBF LTC4224IMS-1#PBF

LTC4216IMS#PBF LTC4212IMS#PBF LTC4260CGN#PBF LTC4227CGN-2#PBF LTC4244IGN#PBF LTC4212CMS#PBF

LT4250HCN8#PBF ADM1276-3ACPZ-RL LTC4226IUD-1#PBF LT1640AHCN8 ADM1075-2ACPZ ADM1075-1ACPZ ADM1073ARUZ

ADM1073ARUZ-REEL7 ADM1075-1ARUZ ADM1075-2ARUZ ADM1170-1AUJZ-RL7 ADM1171-2AUJZ-RL7 ADM1172-1AUJZ-RL7

ADM1172-2AUJZ-RL7 ADM1176-1ARMZ-R7 ADM1177-1ARMZ-R7 ADM1177-2ARMZ-R7 ADM1178-1ARMZ-R7 ADM1275-3ARQZ

ADM1275-1ARQZ ADM1275-3ARQZ-R7 ADM1276-3ACPZ ADM1278-1BCPZ ADM4210-1AUJZ-RL7 ADM1275-2ARQZ

ADM1070ARTZ-REEL7